

IGBT MODULE (F series)

■ Features

- Low Saturation Voltage
- Voltage Drive
- Variety of Power Capacity Series

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	1200	V
Gate-Emitter Voltage	V _{GES}	±20	V
Collector Current	Continuous	I _C	300
	1ms	I _{C pulse}	600
	Continuous	-I _C	300
	1ms	-I _{C pulse}	600
Max. Power Dissipation	P _C	1800	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 to +125	°C
Net. Weight		415	g
Isolation Voltage	AC, 1min.	V _{isol}	2500
Screw Torque	Mounting *1	3.5 [35]	N · m {kg · cm}
	Terminals *2	4.5 [45]	
	Terminals *3	1.7 [17]	

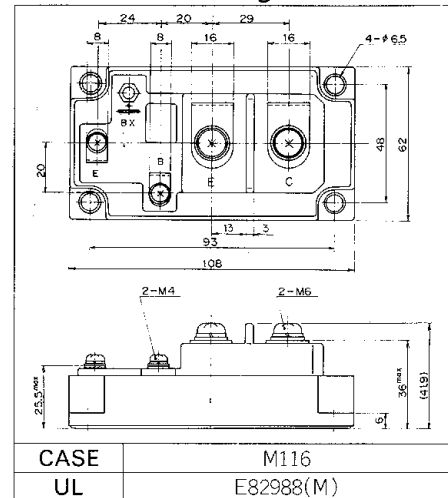
● Electrical Characteristics (T_c=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CEs}	V _{GE} =0V V _{CE} =1200V T _j =25°C			4.0	mA
		V _{GE} =0V V _{CE} =1200V T _j =125°C			—	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =±20V			400	nA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{CE} =20V I _C =300mA	3.0		6.0	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =300A			2.5	V
Input Capacitance	C _{ies}	V _{GE} =0V		54000		pF
Output Capacitance	C _{oes}	V _{CE} =10V		—		
Reverse Transfer Capacitance	C _{res}	f=1MHz		—		
Turn-on Time	t _{on}	V _{CC} =600V I _C =300A	Resistive load			0.8
	t _r					0.6
Turn-off Time	t _{off}	V _{GE} =±15V R _G =2.7Ω	Inductive load			1.5
	t _f					1.0
Diode Forward On-Voltage	V _F	I _F =300A, V _{GE} =0V			2.5	V
Reverse Recovery Time	t _{rr}	I _F =300A, -di/dt=900A/μs V _{GE} =-10V			350	ns

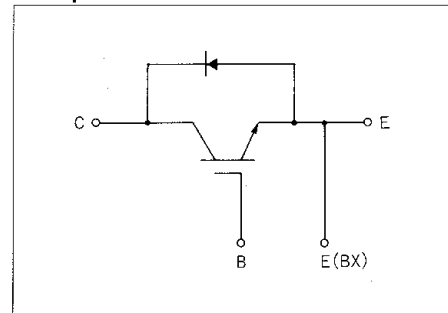
● Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.069	°C/W
	R _{th(j-e)}	Diode			0.111	
	R _{th(c-f)}	With Thermal compound		0.0125		

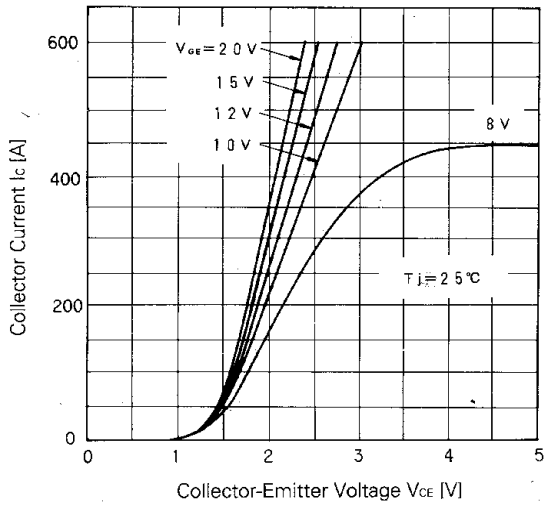
■ Outline Drawings



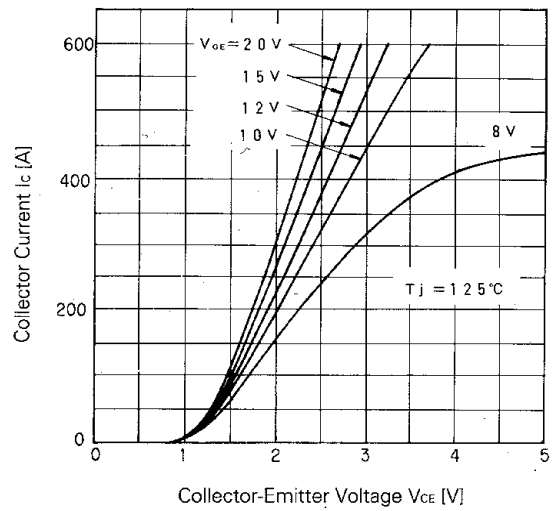
■ Equivalent Circuit Schematic



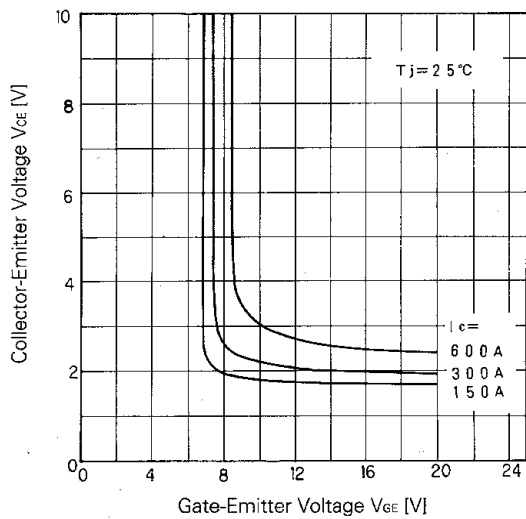
- *1 Recommendable Value 2.5 to 3.5 N·m
25 to 35 kg·cm (M5)
- *2 Recommendable Value 3.5 to 4.5 N·m
35 to 45 kg·cm (M6)
- *3 Recommendable Value 1.3 to 1.7 N·m
13 to 17 kg·cm (M4)



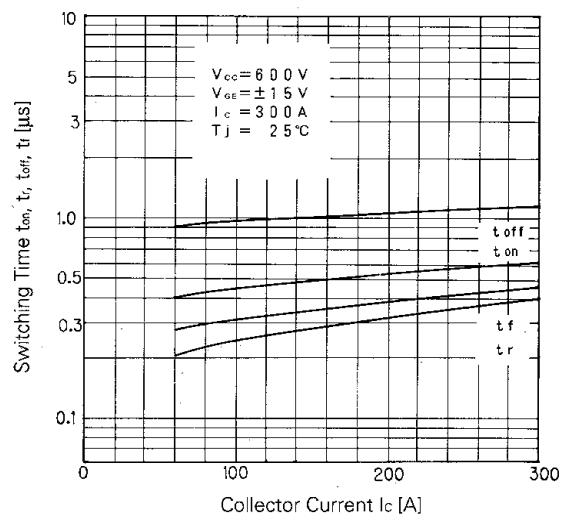
Collector Current vs. Collector-Emitter Voltage



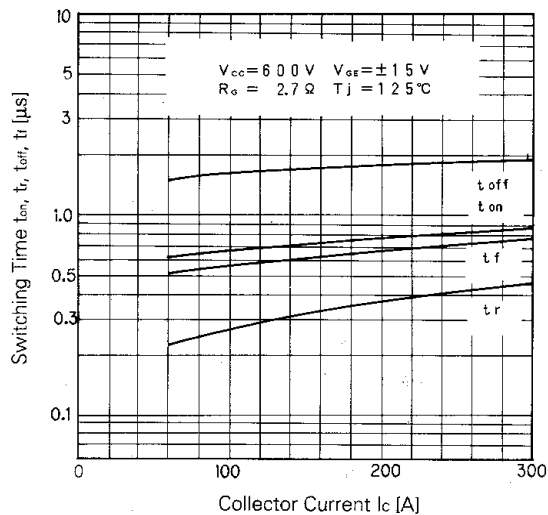
Collector Current vs. Collector-Emitter Voltage



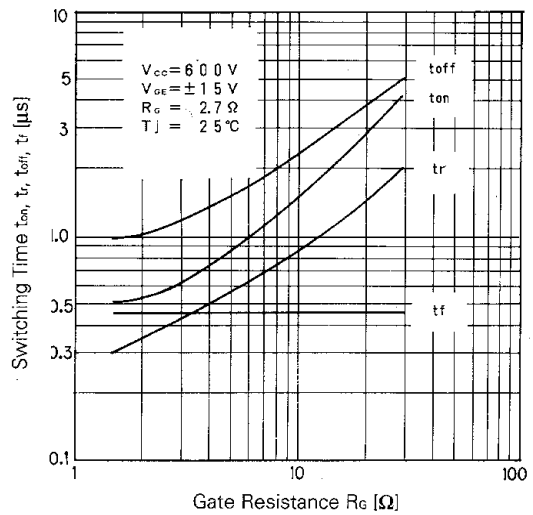
Collector-Emitter Voltage vs. Gate-Emitter Voltage



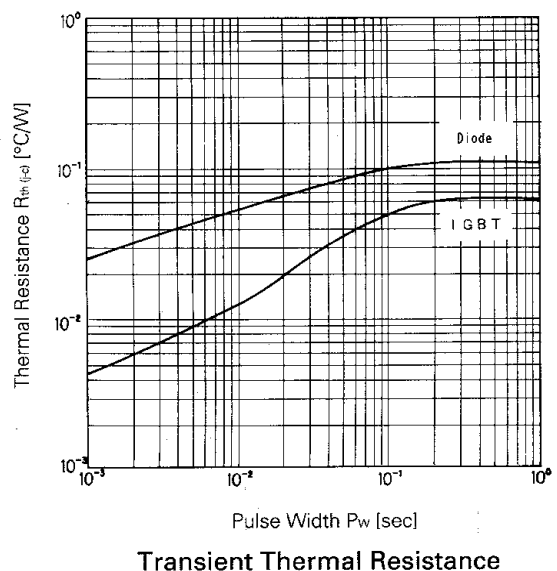
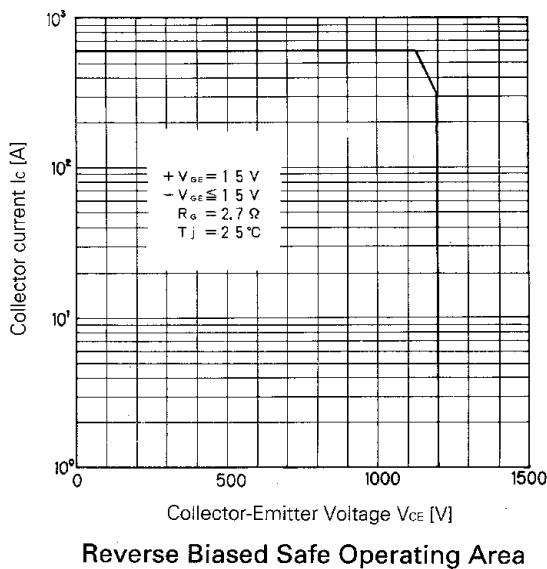
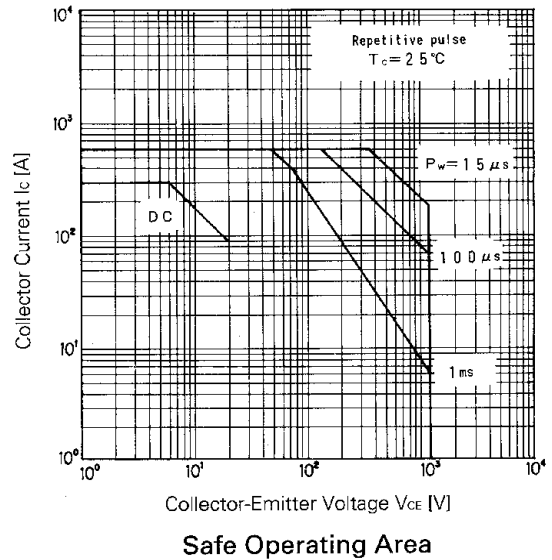
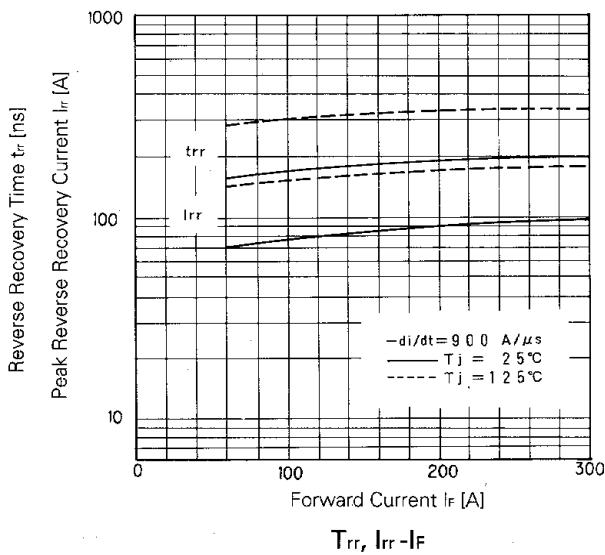
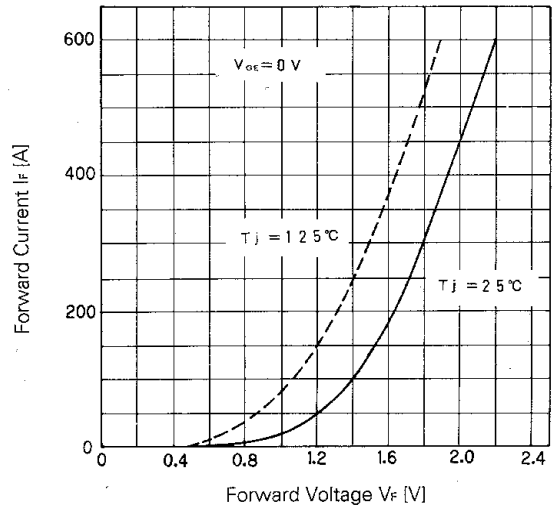
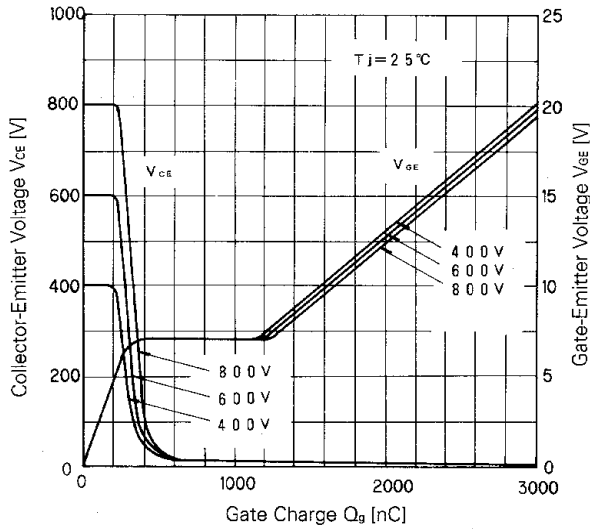
Switching Time



Switching Time



Switching Time-Gate Resistance



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